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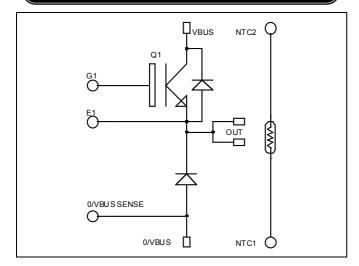
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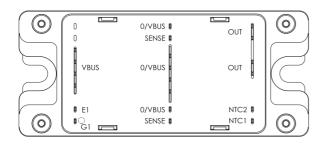
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## Buck chopper Trench + Field Stop IGBT3 Power Module





## APTGT50SK170TG

## $V_{CES} = 1700V$ $I_{C} = 50A$ @ Tc = 80°C

#### Application

- AC and DC motor control
- Switched Mode Power Supplies

#### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring

#### Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
  - Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		1700	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	75	
I <sub>C</sub>	Continuous Conector Current	$T_C = 80^{\circ}C$	50	А
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	100	
V <sub>GE</sub>	Gate – Emitter Voltage		±20	V
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	312	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	100A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 50A$	$T_j = 25^{\circ}C$		2.0 2.4	2.4	V
V <sub>CE(sat)</sub>			$T_{j} = 125^{\circ}C$		2.4		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{mA}$		5.0	5.8	6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

### **Dynamic Characteristics**

Symbol	Characteristic	Test Condition	Test Conditions		Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			4400		
C <sub>oes</sub>	Output Capacitance		$V_{CE} = 25V$		180		pF
C <sub>res</sub>	Reverse Transfer Capacitance	f=1MHz			150		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Swite	ching (25°C)		370		
Tr	Rise Time	$V_{GE} = 15V$			40		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 50A$ $R_{G} = 10\Omega$			650		ns
$T_{\rm f}$	Fall Time				180		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 900V$ $I_C = 50A$			400		
Tr	Rise Time				50		ns
T <sub>d(off)</sub>	Turn-off Delay Time				800		
T <sub>f</sub>	Fall Time	$R_G = 10\Omega$			300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125^{\circ}C$		16		mJ
E <sub>off</sub>	Turn-off Switching Energy	$I_{\rm C} = 50 A$ $R_{\rm G} = 10 \Omega$	$T_j = 125^{\circ}C$		15		1113

### Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			1700			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =1700V	$T_j = 25^{\circ}C$			250	μA
*KM	international intervense Deunage Carteine	V <sub>K</sub> 1700V	$T_{j} = 125^{\circ}C$			500	μΠ
I <sub>F</sub>	DC Forward Current		$Tc = 80^{\circ}C$		50		А
V <sub>F</sub>	Diode Forward Voltage	$I_F = 50A$	$T_i = 25^{\circ}C$		1.8	2.2	V
• F	Diode Forward Voltage		$T_i = 125^{\circ}C$		1.9		•
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25^{\circ}C$		385		ns
٩r	Reverse Recovery Time	T 50 4	$T_{j} = 125^{\circ}C$		490		115
0	$Q_{rr}$ Reverse Recovery Charge $I_F = 50A$ $V_R = 900V$ $di/dt = 800A/\mu s$	$I_F = 50A$ $V_F = 000V$	$T_j = 25^{\circ}C$		14		uС
Qrr		$T_{j} = 125^{\circ}C$		23		μC	
Б	Reverse Recovery Energy		$T_j = 25^{\circ}C$		6		mJ
Er			$T_j = 125^{\circ}C$		12		111J



## APTGT50SK170TG

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K
	<i>D</i>				

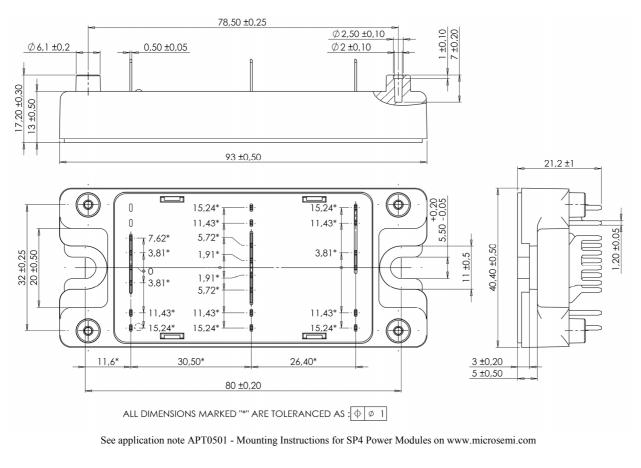
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermis  
R<sub>T</sub>: Therm

Thermistor temperature T: Thermistor value at T

### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance		IGBT Diode			0.4	°C/W
<b>R</b> <sub>th</sub> JC					0.7	$C_{i}$ w	
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
TJ	Operating junction temperature range		-40		150		
T <sub>STG</sub>	Storage Temperature Range		-40		125	°C	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

#### SP4 Package outline (dimensions in mm)

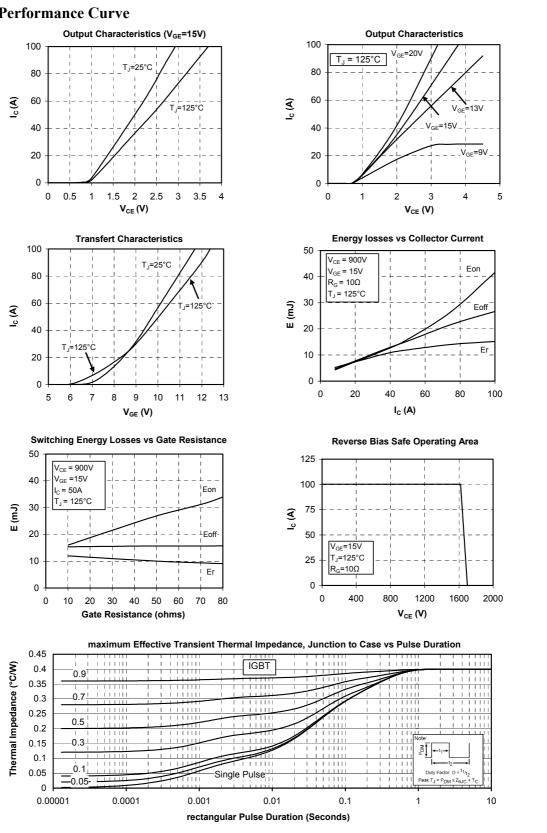


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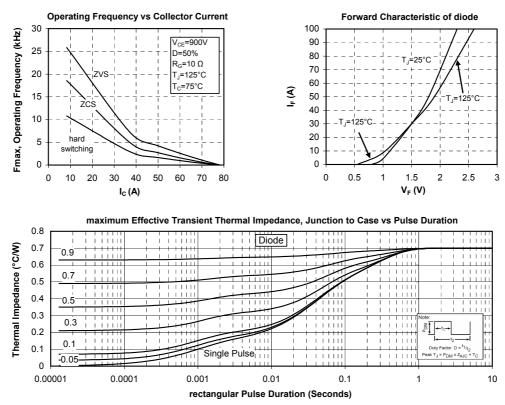
#### **Typical Performance Curve**

## APTGT50SK170TG





## APTGT50SK170TG





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